# BLL8H1214L-250; BLL8H1214LS-250 LDMOS L-band radar power transistor Rev. 3 — 1 September 2015

**AMPLEON** 

Product data sheet

#### **Product profile** 1.

#### 1.1 General description

250 W LDMOS power transistor intended for L-band radar applications in the 1.2 GHz to 1.4 GHz range.

#### **Test information** Table 1.

Typical RF performance at  $T_{case}$  = 25 °C;  $t_p$  = 300  $\mu$ s;  $\delta$  = 10 %;  $I_{Da}$  = 100 mA; in a class-AB production test circuit.

| Test signal | f          | V <sub>DS</sub> | $P_L$ | Gp   | $\eta_D$ | t <sub>r</sub> | t <sub>f</sub> |
|-------------|------------|-----------------|-------|------|----------|----------------|----------------|
|             | (GHz)      | (V)             | (W)   | (dB) | (%)      | (ns)           | (ns)           |
| pulsed RF   | 1.2 to 1.4 | 50              | 250   | 17   | 55       | 15             | 5              |

#### 1.2 Features and benefits

- Easy power control
- Integrated dual side ESD protection
- High flexibility with respect to pulse formats
- Excellent ruggedness
- High efficiency
- Excellent thermal stability
- Designed for broadband operation (1.2 GHz to 1.4 GHz)
- Internally matched for ease of use
- Compliant to Directive 2002/95/EC, regarding restriction of hazardous substances (RoHS)

#### 1.3 Applications

 L-band power amplifiers for radar applications in the 1.2 GHz to 1.4 GHz frequency range

## 2. Pinning information

Table 2. Pinning

| Pin       | Description       | Simplified outline | Graphic symbol    |
|-----------|-------------------|--------------------|-------------------|
| BLL8H1214 | 4L-250 (SOT502A)  |                    |                   |
| 1         | drain             |                    |                   |
| 2         | gate              | 5 1 3              | ئے ا              |
| 3         | source 11         |                    | 2 — 3<br>sym112   |
| BLL8H1214 | 1LS-250 (SOT502B) |                    | -                 |
| 1         | drain             |                    |                   |
| 2         | gate              | 1 3                | <u>1</u><br>لـــا |
| 3         | source [1         |                    | 2 — 3<br>sym112   |

<sup>[1]</sup> Connected to flange.

## 3. Ordering information

Table 3. Ordering information

| Type number     | Packag | Package  |         |  |  |
|-----------------|--------|--|---------|--|--|
|                 | Name   | Description  | Version |  |  |
| BLL8H1214L-250  | -      | flanged ceramic package; 2 mounting holes; 2 leads | SOT502A |  |  |
| BLL8H1214LS-250 | -      | earless flanged ceramic package; 2 leads           | SOT502B |  |  |

## 4. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

| Symbol           | Parameter            | Conditions | Min | Max  | Unit |
|------------------|----------------------|------------|-----|------|------|
| $V_{DS}$         | drain-source voltage |            | -   | 100  | V    |
| $V_{GS}$         | gate-source voltage  |            | -6  | +13  | V    |
| T <sub>stg</sub> | storage temperature  |            | -65 | +150 | °C   |
| Tj               | junction temperature | [1]        | -   | 225  | °C   |

Continuous use at maximum temperature will affect the reliability, for details refer to the on-line MTF calculator.

## 5. Thermal characteristics

Table 5. Thermal characteristics

| Symbol               | Parameter                        | Conditions  | Тур  | Unit |
|----------------------|----------------------------------|---|------|------|
| Z <sub>th(j-c)</sub> | transient thermal impedance from | T <sub>case</sub> = 85 °C; P <sub>L</sub> = 250 W |      |      |
|                      | junction to case                 | $t_p$ = 100 $\mu$ s; $\delta$ = 10 %              | 0.10 | K/W  |
|                      |                                  | $t_p$ = 200 $\mu$ s; $\delta$ = 10 %              | 0.13 | K/W  |
|                      |                                  | $t_p$ = 300 $\mu$ s; $\delta$ = 10 %              | 0.15 | K/W  |
|                      |                                  | $t_p$ = 100 $\mu$ s; $\delta$ = 20 %              | 0.14 | K/W  |
|                      |                                  | $t_p$ = 500 $\mu$ s; $\delta$ = 20 %              | 0.20 | K/W  |

## 6. Characteristics

Table 6. DC characteristics

 $T_i = 25 \, ^{\circ}C$ .

| Symbol               | Parameter                        | Conditions   | Min | Тур | Max  | Unit |
|----------------------|----------------------------------|--|-----|-----|------|------|
| V <sub>(BR)DSS</sub> | drain-source breakdown voltage   | $V_{GS} = 0 \text{ V}; I_D = 2.7 \text{ mA}$       | 100 | -   | -    | V    |
| $V_{GS(th)}$         | gate-source threshold voltage    | V <sub>DS</sub> = 10 V; I <sub>D</sub> = 270 mA    | 1.3 | 1.8 | 2.25 | V    |
| I <sub>DSS</sub>     | drain leakage current            | V <sub>GS</sub> = 0 V; V <sub>DS</sub> = 50 V      | -   | -   | 1.4  | μΑ   |
| I <sub>DSX</sub>     | drain cut-off current            | $V_{GS} = V_{GS(th)} + 3.75 V;$<br>$V_{DS} = 10 V$ | 32  | 42  | -    | A    |
| I <sub>GSS</sub>     | gate leakage current             | V <sub>GS</sub> = 11 V; V <sub>DS</sub> = 0 V      | -   | -   | 140  | nA   |
| 9 <sub>fs</sub>      | forward transconductance         | V <sub>DS</sub> = 10 V; I <sub>D</sub> = 270 mA    | 1.6 | 2.3 | -    | S    |
| R <sub>DS(on)</sub>  | drain-source on-state resistance | $V_{GS} = V_{GS(th)} + 3.75 V;$<br>$I_D = 9.5 A$   | -   | 100 | 169  | mΩ   |

#### Table 7. RF characteristics

Test signal: pulsed RF;  $t_p$  = 300  $\mu$ s;  $\delta$  = 10 %; RF performance at  $V_{DS}$  = 50 V;  $I_{Dq}$  = 100 mA;  $T_{case}$  = 25 °C; unless otherwise specified, in a class-AB production test circuit.

| Symbol                    | Parameter                             | Conditions             | Min | Тур | Max | Unit |
|---------------------------|---------------------------------------|------------------------|-----|-----|-----|------|
| $V_{DS}$                  | drain-source voltage                  | P <sub>L</sub> = 250 W | -   | -   | 50  | V    |
| Gp                        | power gain                            | P <sub>L</sub> = 250 W | 15  | 17  | -   | dB   |
| RLin                      | input return loss                     | P <sub>L</sub> = 250 W | -   | -10 | -   | dB   |
| P <sub>L(1dB)</sub>       | output power at 1 dB gain compression |                        | -   | 300 | -   | W    |
| $\eta_{D}$                | drain efficiency                      | P <sub>L</sub> = 250 W | 49  | 55  | -   | %    |
| P <sub>droop(pulse)</sub> | pulse droop power                     | P <sub>L</sub> = 250 W | -   | 0   | 0.3 | dB   |
| t <sub>r</sub>            | rise time                             | P <sub>L</sub> = 250 W | -   | 15  | -   | ns   |
| t <sub>f</sub>            | fall time                             | P <sub>L</sub> = 250 W | -   | 5   | -   | ns   |

## 7. Application information

#### 7.1 Ruggedness in class-AB operation

The BLL8H1214L-250 and BLL8H1214LS-250 are capable of withstanding a load mismatch corresponding to VSWR = 10 : 1 through all phases under the following conditions:  $V_{DS}$  = 50 V;  $I_{Dq}$  = 100 mA;  $P_L$  = 250 W;  $I_p$  = 300  $\mu$ s;  $\delta$  = 10 %.

#### 7.2 Impedance information

Table 8. Typical impedance

Typical values unless otherwise specified.

| f     | Z <sub>S</sub> | Z <sub>L</sub> |
|-------|----------------|----------------|
| (GHz) | (Ω)            | (Ω)            |
| 1.2   | 1.268 – j2.623 | 2.987 – j1.664 |
| 1.3   | 2.193 – j2.457 | 2.162 – j1.326 |
| 1.4   | 2.359 – j2.052 | 1.604 – j1.887 |

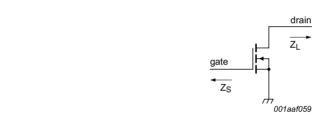
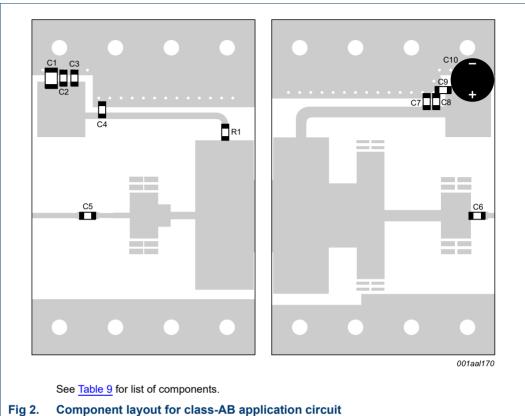


Fig 1. Definition of transistor impedance

## 7.3 Application circuit



Component layout for class-AB application circuit

Table 9. List of components

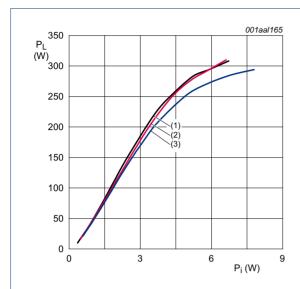
See Figure 2.

Striplines are on a Rogers Duroid 6006 Printed-Circuit Board (PCB);  $\varepsilon_r = 6.15$  F/m; thickness = 0.64 mm

| Component | Description                       | Value           | Remarks  |
|-----------|-----------------------------------|-----------------|----------|
| C1        | multilayer ceramic chip capacitor | 10 μF, 35 V [1] |          |
| C2, C4    | multilayer ceramic chip capacitor | 51 pF [2]       |          |
| C3, C8    | multilayer ceramic chip capacitor | 1 nF [2]        |          |
| C5        | multilayer ceramic chip capacitor | 82 pF [3]       |          |
| C6, C7    | multilayer ceramic chip capacitor | 56 pF [3]       |          |
| C9        | multilayer ceramic chip capacitor | 100 pF [3]      |          |
| C10       | electrolytic capacitor            | 47 μF, 63 V     |          |
| R1        | SMD resistor                      | 10 Ω            | SMD 0603 |

- [1] American Technical Ceramics type 100A or capacitor of same quality.
- American Technical Ceramics type 100B or capacitor of same quality.
- American Technical Ceramics type 800B or capacitor of same quality.

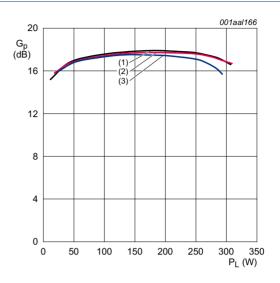
## 7.4 RF performance graphs



 $V_{DS}$  = 50 V;  $t_p$  = 300  $\mu s;$   $\delta$  = 10 %;  $I_{Dq}$  = 100 mA.

- (1) f = 1200 MHz
- (2) f = 1300 MHz
- (3) f = 1400 MHz

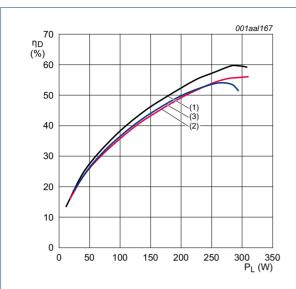
Fig 3. Output power as a function of input power; typical values



 $V_{DS}$  = 50 V;  $t_p$  = 300  $\mu$ s;  $\delta$  = 10 %;  $I_{Dq}$  = 100 mA.

- (1) f = 1200 MHz
- (2) f = 1300 MHz
- (3) f = 1400 MHz

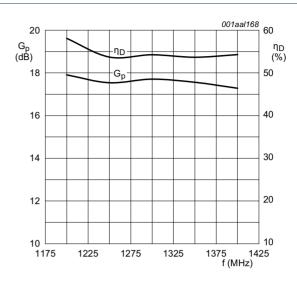
Fig 4. Power gain as a function of output power; typical values



 $V_{DS}$  = 50 V;  $t_p$  = 300  $\mu s$ ;  $\delta$  = 10 %;  $I_{Dq}$  = 100 mA.

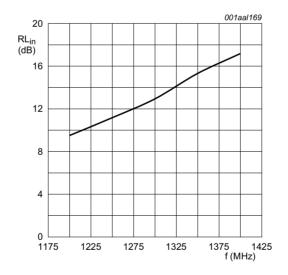
- (1) f = 1200 MHz
- (2) f = 1300 MHz
- (3) f = 1400 MHz

Fig 5. Drain efficiency as a function of output power; typical values



 $P_L$  = 250 W;  $V_{DS}$  = 50 V;  $t_p$  = 300  $\mu s;$   $\delta$  = 10 %;  $I_{Dq}$  = 100 mA.

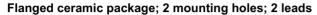
Fig 6. Power gain and drain efficiency as function of frequency; typical values



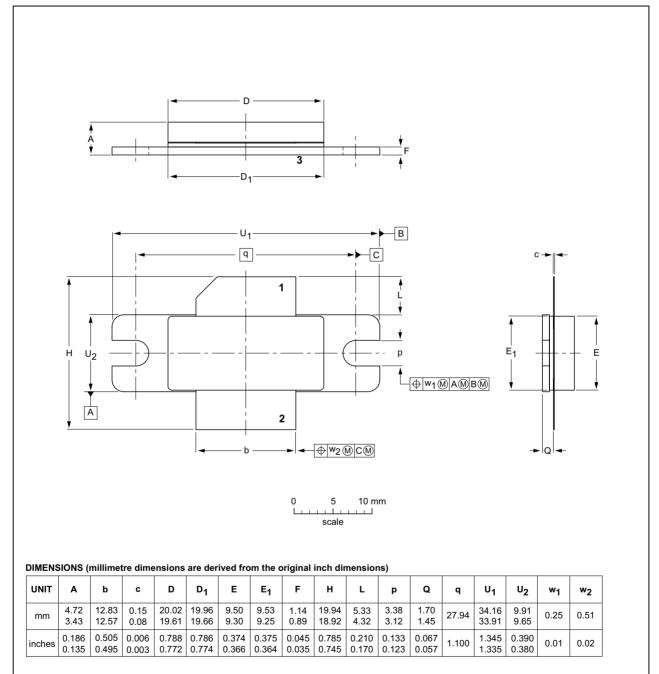
 $P_L$  = 250 W;  $V_{DS}$  = 50 V;  $t_p$  = 300  $\mu s;$   $\delta$  = 10 %;  $I_{Dq}$  = 100 mA.

Fig 7. Input return loss as a function of frequency; typical value

## 8. Package outline



SOT502A



OUTLINE VERSIONREFERENCESEUROPEAN PROJECTIONISSUE DATESOT502AJEDECJEITA-03-01-10-12-05-02

Fig 8. Package outline SOT502A

#### Earless flanged ceramic package; 2 leads

SOT502B

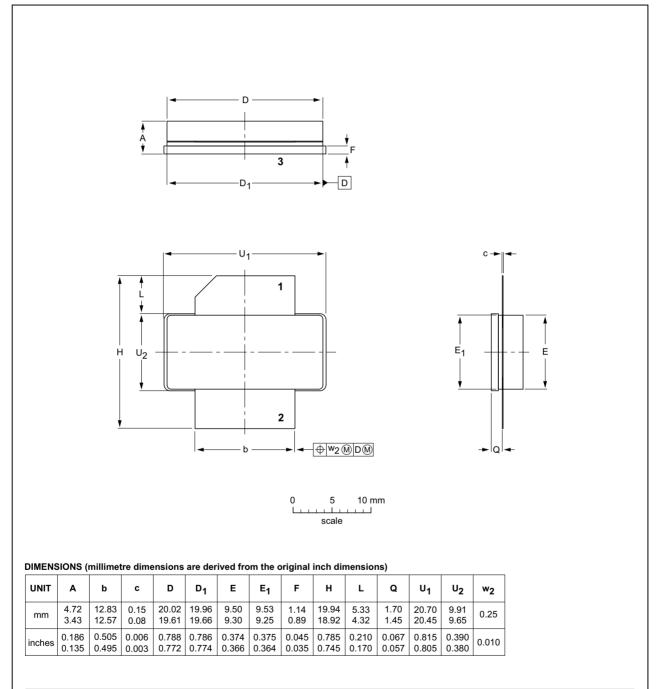


Fig 9. Package outline SOT502B

IEC

OUTLINE

VERSION

SOT502B

JEITA

**REFERENCES** 

**JEDEC** 

**ISSUE DATE** 

07-05-09

12-05-02

EUROPEAN

**PROJECTION** 

## 9. Handling information

#### CAUTION



This device is sensitive to ElectroStatic Discharge (ESD). Observe precautions for handling electrostatic sensitive devices.

Such precautions are described in the *ANSI/ESD S20.20*, *IEC/ST 61340-5*, *JESD625-A* or equivalent standards.

## 10. Abbreviations

Table 10. Abbreviations

| Acronym | Description                                 |  |
|---------|---|--|
| ESD     | lectroStatic Discharge                      |  |
| L-band  | ong wave Band                               |  |
| LDMOS   | aterally Diffused Metal-Oxide Semiconductor |  |
| MTF     | Median Time to Failure                      |  |
| SMD     | Surface Mounted Device                      |  |
| VSWR    | Voltage Standing-Wave Ratio                 |  |

## 11. Revision history

Table 11. Revision history

| Document ID                  | Release date   | Data sheet status    | Change notice | Supersedes                      |  |
|------------------------------|--|----------------------|---------------|---------------------------------|--|
| BLL8H1214L-250_1214LS-250#3  | 20150901   | Product data sheet   | -             | BLL8H1214L-250_1214LS-250<br>#2 |  |
| Modifications:               | <ul> <li>The format of this document has been redesigned to comply with the new identity guidelines of Ampleon.</li> <li>Legal texts have been adapted to the new company name where appropriate.</li> </ul> |                      |               |                                 |  |
| BLL8H1214L-250_1214LS-250 #2 | 20150113   | Product data sheet   | -             | BLL8H1214L-250_1214LS-250<br>#1 |  |
| BLL8H1214L-250_1214LS-250 #1 | 20140930   | Objective data sheet | -             | -                               |  |

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| Document status[1][2]          | Product status[3] | Definition  |  |
|--------------------------------|-------------------|---|--|
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# BLL8H1214L(S)-250

#### LDMOS L-band radar power transistor

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## **AMPLEON**

# BLL8H1214L(S)-250

## LDMOS L-band radar power transistor

## 14. Contents

| 1    | Product profile                  | . 1 |
|------|----------------------------------|-----|
| 1.1  | General description              | . 1 |
| 1.2  | Features and benefits            |     |
| 1.3  | Applications                     | . 1 |
| 2    | Pinning information              | . 2 |
| 3    | Ordering information             | . 2 |
| 4    | Limiting values                  | . 2 |
| 5    | Thermal characteristics          | . 3 |
| 6    | Characteristics                  | . 3 |
| 7    | Application information          | . 4 |
| 7.1  | Ruggedness in class-AB operation |     |
| 7.2  | Impedance information            |     |
| 7.3  | Application circuit              | . 5 |
| 7.4  | RF performance graphs            | . 6 |
| 8    | Package outline                  | . 8 |
| 9    | Handling information             | 10  |
| 10   | Abbreviations                    | 10  |
| 11   | Revision history                 | 10  |
| 12   | Legal information                | 11  |
| 12.1 | Data sheet status                | 11  |
| 12.2 | Definitions                      | 11  |
| 12.3 | Disclaimers                      | 11  |
| 12.4 | Trademarks                       | 12  |
| 13   | Contact information              | 12  |
| 14   | Contents                         | 13  |

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